

Data sheet acquired from Harris Semiconductor SCHS148A

CD74HC139, CD74HCT139

High-Speed CMOS Logic Dual 2-to-4 Line Decoder/Demultiplexer

September 1997 - Revised May 1999

Features

- · Multifunction Capability
 - Binary to 1 of 4 Decoders or 1 to 4 Line Demultiplexer
- Active Low Mutually Exclusive Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1 μA at VOL, VOH
- Memory Decoding, Data Routing, Code Conversion

Description

The CD74HC139 and CD74HCT139 devices contain two independent binary to one of four decoders each with a single active low enable input ($\overline{1E}$ or $\overline{2E}$). Data on the select inputs (1A0 and 1A1 or 2A0 and 2A1) cause one of the four normally high outputs to go low.

If the enable input is high all four outputs remain high. For demultiplexer operation the enable input is the data input. The enable input also functions as a chip select when these devices are cascaded. This device is functionally the same as the CD4556B and is pin compatible with it.

The outputs of these devices can drive 10 low power Schottky TTL equivalent loads. The 74HCT logic family is functionally as well as pin equivalent to the 74LS logic family.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74HC139E	-55 to 125	16 Ld PDIP	E16.3
CD74HCT139E	-55 to 125	16 Ld PDIP	E16.3
CD74HC139M	-55 to 125	16 Ld SOIC	M16.15
CD74HCT139M	-55 to 125	16 Ld SOIC	M16.15

NOTES:

- When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Die is available which meets all electrical specifications. Please contact your local sales office or customer service for ordering information.

Pinout

CD74HC139, CD74HCT139 (PDIP, SOIC) TOP VIEW

 1E
 1

 1A0
 2

 1A1
 3

 1Y0
 4

 1Y1
 5

 1Y2
 6

 1Y3
 7

 1Y3
 7

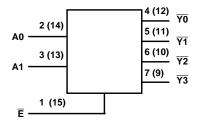
 1Y3
 7

 1Y3
 7

 1Y3
 9

 2Y3

Functional Diagram

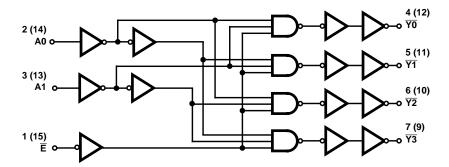


TRUTH TABLE

INPUTS	ENABLE	SELECT	OUTPUTS								
Ē	A1 A0		<u></u> 73	<u>Y3</u> <u>Y2</u>		<u>Y0</u>					
0	0	0	1	1	1	0					
0	0	1	1	1	0	1					
0	1	0	1	0	1	1					
0	1	1	0	1	1	1					
1	X	Х	1	1	1	1					

NOTE: X = Don't Care, Logic 1 = High, Logic 0 = Low

Logic Diagram



Absolute Maximum Ratings

Thermal Information

Thermal Resistance (Typical, Note 3)	θ_{JA} (°C/W)
PDIP Package	90
SOIC Package	115
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

3. $\theta_{\mbox{\scriptsize JA}}$ is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

		TE: CONDI	_	v _{cc}		25°C		-40°C 1	O 85°C	-55 ⁰ C T	O 125 ⁰ C	
PARAMETER		(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS		
HC TYPES							-	-	-			
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	•	-	3.15	-	3.15	-	V
				6	4.2	•	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	VoH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	٧
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	٧
OMOO Edado			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE Educa			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWOO LOAGS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
I I L LOGOS			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	ı	8	-	80	-	160	μΑ

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}		25°C			O 85°C	-55°C T		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	Ī	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	=	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load (Note 4)	Δl _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
All	0.7

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

Switching Specifications Input t_{r} , $t_{f} = 6 \text{ns}$

		TEST	v _{cc}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	145	-	180	-	220	ns
A0, A1 to Outputs			4.5	-	-	29	-	36	-	44	ns
			6	-	-	25	-	31	-	38	ns
E to Outputs	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	135	-	170	-	205	ns
			4.5	-	-	27	-	34	-	41	ns
			6	-	-	23	-	29	-	35	ns
Select to Output	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	12	-	-	-	-	-	ns
Enable to Output	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	11	-	-	-	-	-	ns

^{4.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

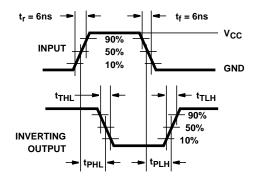
Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST	V _{CC}		25 ⁰ C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Transition Time (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Power Dissipation Capacitance, (Notes 5, 6)	C _{PD}	-	5	-	55	-	-	-	-	-	pF
Input Capacitance	C _{IN}	=	-	-	-	10	-	10	-	10	pF
HCT TYPES	•										
Propagation Delay											
A0, A1 to Outputs	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
Ē to Outputs	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
Select to Output	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	14	-	-	-	-	-	ns
Enable to Output	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	14	-	-	-	-	-	ns
Output Transition Time (Figure 2)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Power Dissipation Capacitance, (Notes 5, 6)	C _{PD}	-	5	-	59	-	-	-	-	-	pF
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF

NOTES:

- 5. $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per decoder/demux.
- 6. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where: $f_i = Input$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.

Test Circuits and Waveforms





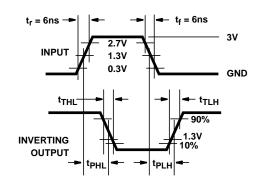


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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